NSN 5961-01-061-9858

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View Online at https://aerobasegroup.com/nsn/5961-01-061-9858 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** 1.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Function For Which Designed:** Switching **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 1.3 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 88818-a532a062 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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